

COBP PHOTO REFLECTOR

■ GENERAL DESCRIPTION

The NJL5902R-1 is the compact surface mount type photo reflector in which Lead (Pb)-free reflow soldering permitted (260°C, 2times). The NJL5902R-1 reduced to the operating dark current of 1/6 compared with our conventional products/NJL5901R-1, and has realized the high S/N ratio in the combination of the high output LED and a high sensitivity Si photo-transistor.

■ FEATURES

- High S/N ratio
- Operating dark current: 0.5 μ A max.
- Pb free solder re-flowing permitted: 260°C, 2times
- Miniature, thin, surface mount: 1.6mm \times 2.0mm \times 0.6mm
- Built-in visible light cut-off filter

■ APPLICATIONS

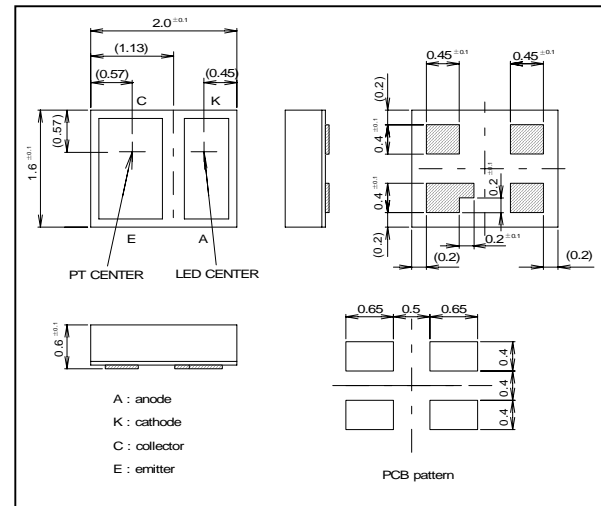
- Detecting the location of optical pickup head for CD/DVD
- Detecting the location of lens for DSC and Cellular phone's camera module
- Detecting the rotation of various motors
- Paper edge detection and mechanism timing detection of facsimile, copy machine etc.

■ ABSOLUTE MAXIMUM RATINGS (Ta=25°C)

PARAMETER	SYMBOL	RATINGS	UNIT
Emitter			
Forward Current (Continuous)	IF	30	mA
Reverse Voltage (Continuous)	VR	6	V
Power Dissipation	PD	45	mW
Detector			
Collector-Emitter Voltage	VCEO	16	V
Emitter-Collector Voltage	VECO	6	V
Collector Current	IC	10	mA
Collector Power Dissipation	PC	25	mW
Coupled			
Total Power Dissipation	Ptot	60	mW
Operating Temperature	Topr	-30 to +85	°C
Storage Temperature	Tstg	-40 to +100	°C
Reflow Soldering Temperature	Tsol	260	°C

■ OUTLINE (typ.)

Unit : mm



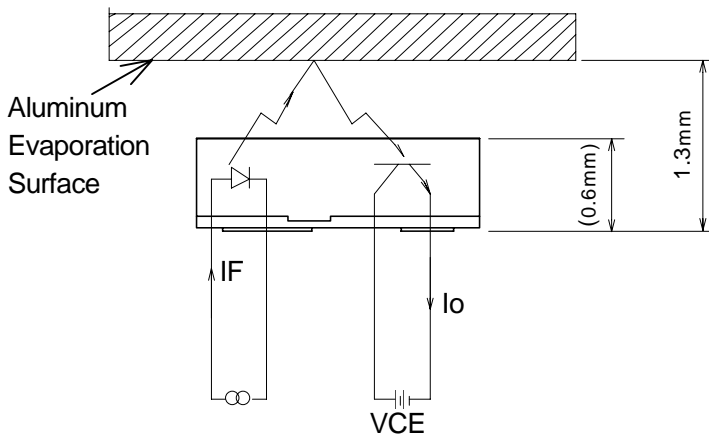
■ ELECTRO-OPTICAL CHARACTERISTICS (Ta=25°C)

PARAMETER	SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNIT
Emitter						
Forward Voltage	VF	IF=4mA	0.9	—	1.3	V
Reverse Current	IR	VR=6V	—	—	10	μ A
Capacitance	Ct	VR=0V, f=1MHz	—	25	—	pF
Detector						
Dark Current	ICEO	VCE=10V	—	—	0.2	μ A
Collector-Emitter Voltage	VCEO	IC=100 μ A	16	—	—	V
Coupled						
Output Current	IO	IF=4mA, VCE=2V, d=0.7mm	160	—	400	μ A
Operating Dark Current *1	ICEOD	IF=4mA, VCE=2V	—	—	0.5	μ A
Rise Time	tr	IO=100 μ A, VCE=2V, RL=1K Ω , d=0.7mm	—	30	—	μ s
Fall Time	tf	IO=100 μ A, VCE=2V, RL=1K Ω , d=0.7mm	—	30	—	μ s

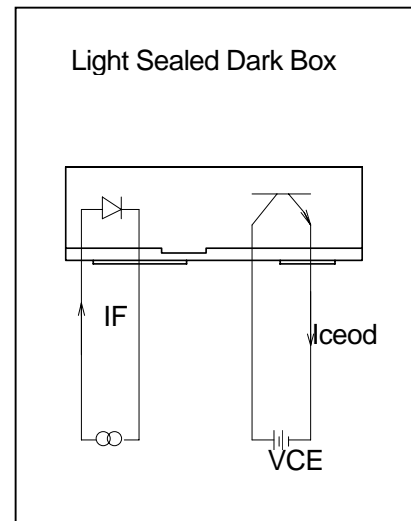
*1 Icoed may increase according to the periphery situation of the surface mounted product.

■ OUTPUT CURRENT TEST CONDITION

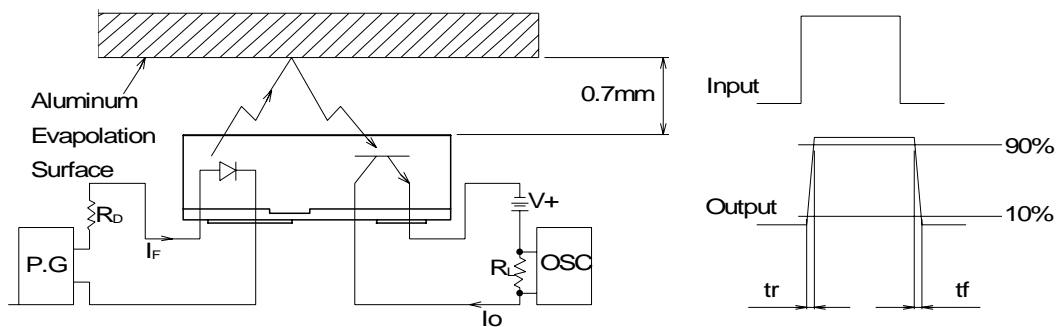
The infrared signal from LED is reflected at the aluminum surface.



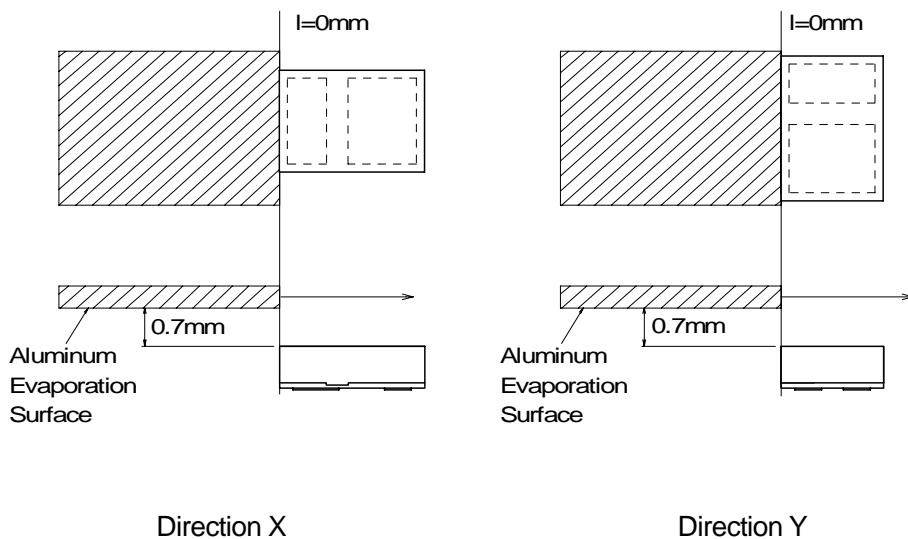
■ DARK CURRENT TEST CONDITION



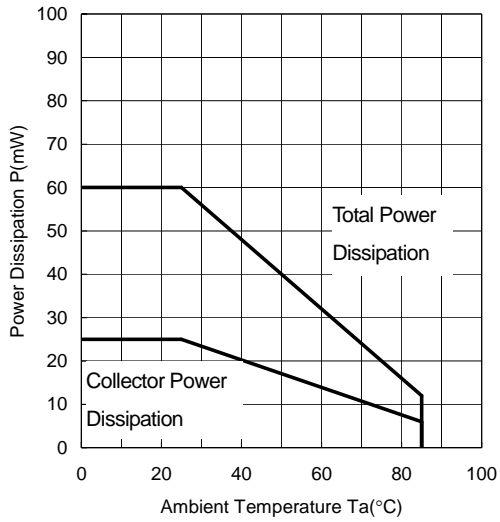
■ RESPONSE TIME TEST CONDITION



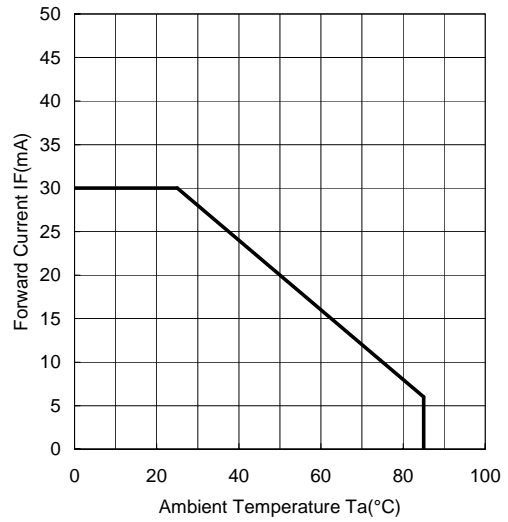
■ EDGE RESPONSE TEST CONDITION



Power Dissipation vs. Temperature

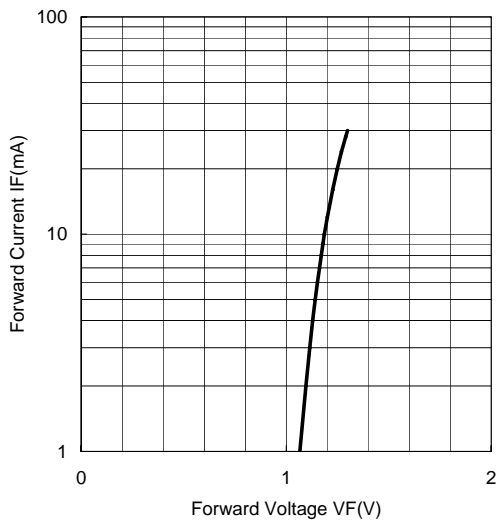


Forward Current vs. Temperature

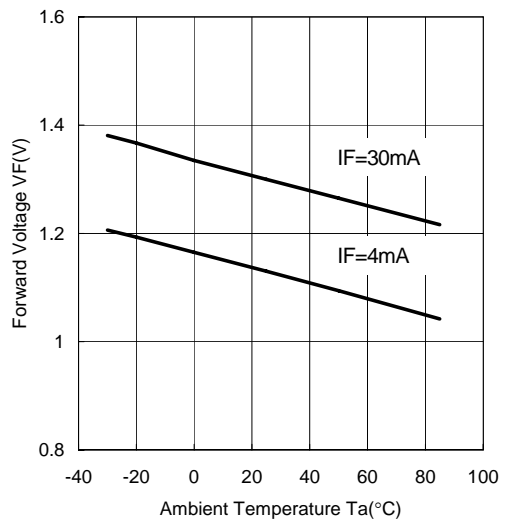


■ TYPICAL CHARACTERISTICS

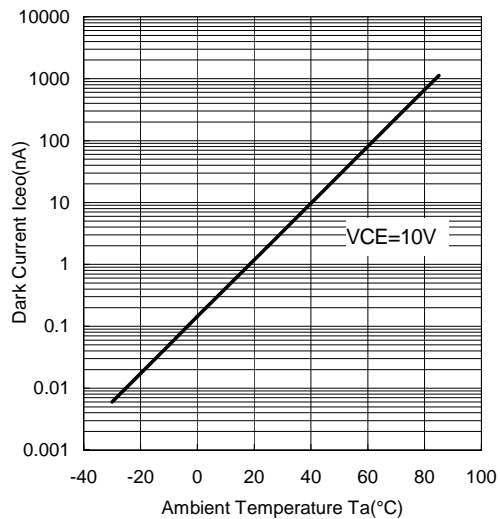
Forward Voltage vs. Forward Current



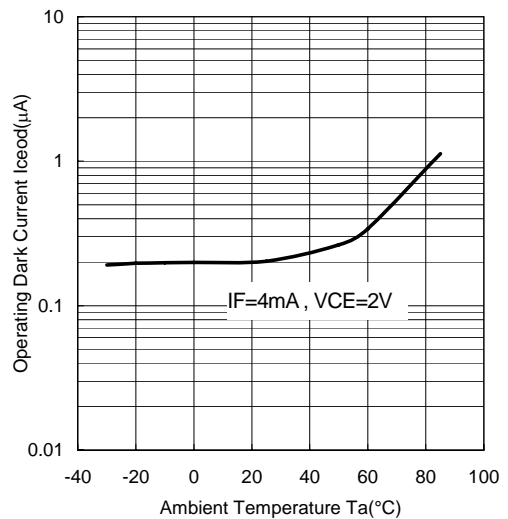
Forward Voltage vs. Temperature



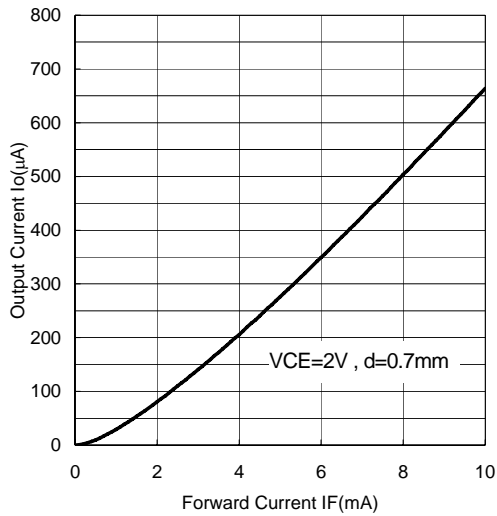
Dark Current vs. Temperature



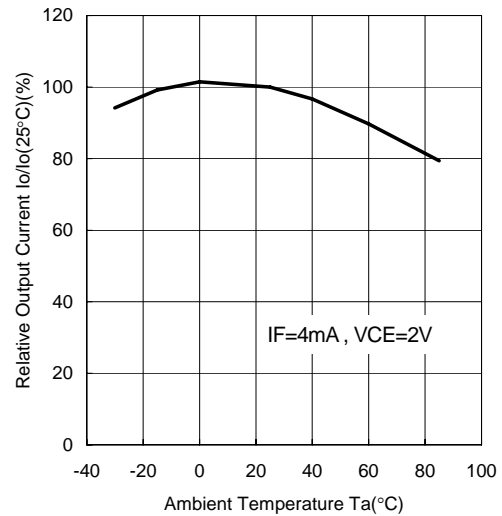
Operating Dark Current vs. Temperature



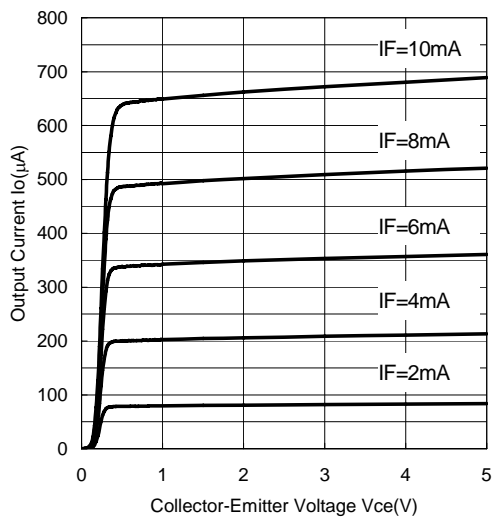
Output Current vs. Forward Current (Ta=25°C)



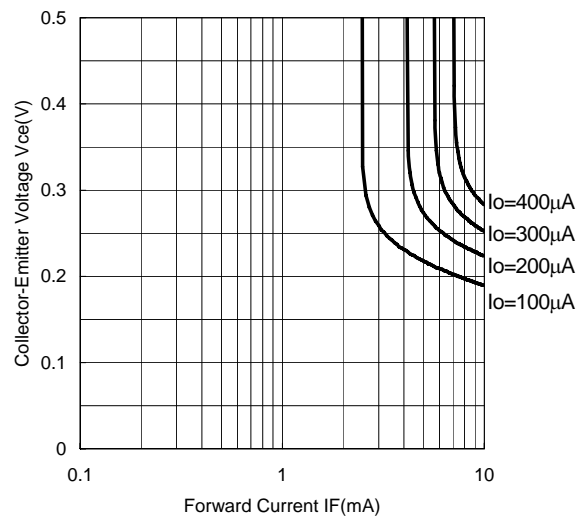
Output Current vs. Temperature



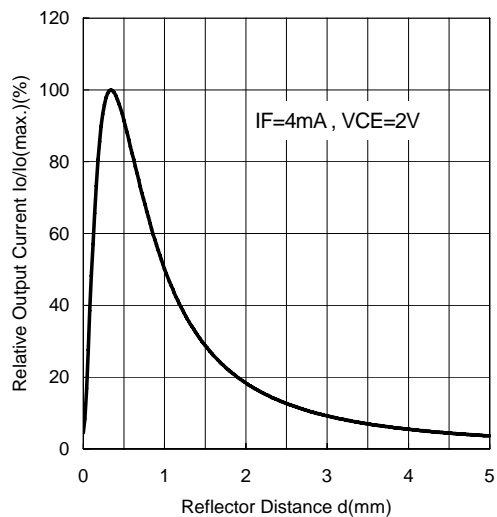
Output Characteristics (Ta=25°C)



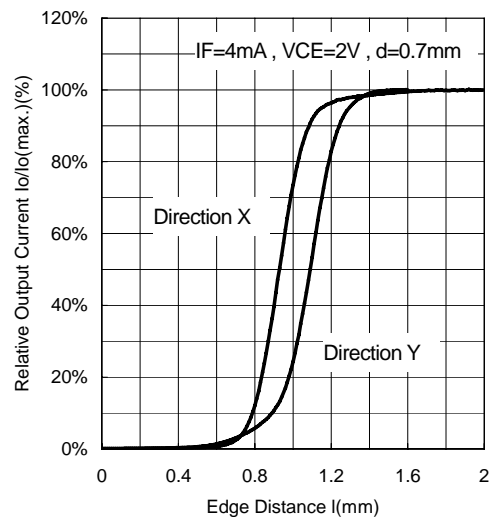
Vce Saturation (Ta=25°C)



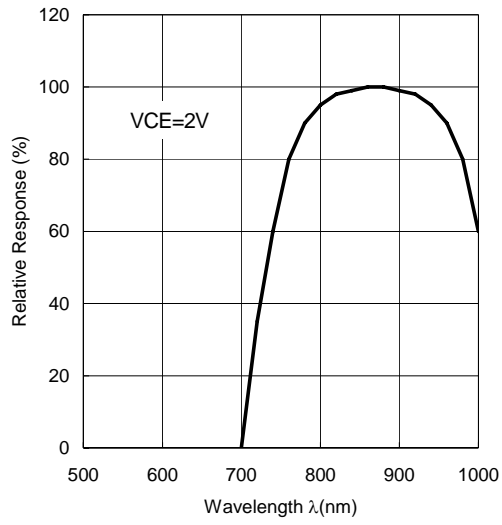
Output Current vs. Distance (Ta=25°C)



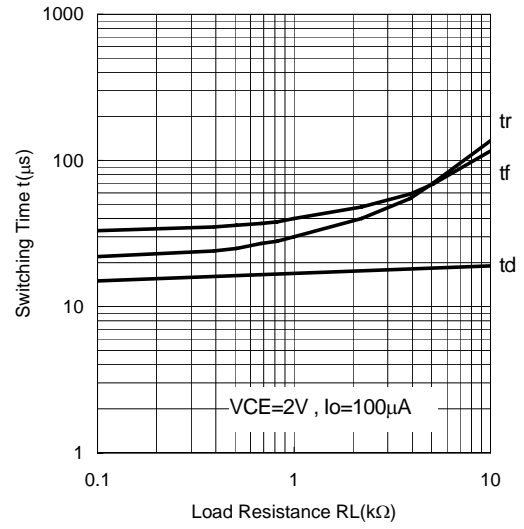
Output Current vs. Edge Distance (Ta=25°C)



Spectral Response (Ta=25°C)



Switching Time vs. Load Resistance (Ta=25°C)



PRECAUTION FOR HANDLING

1. Soldering to actual circuit board

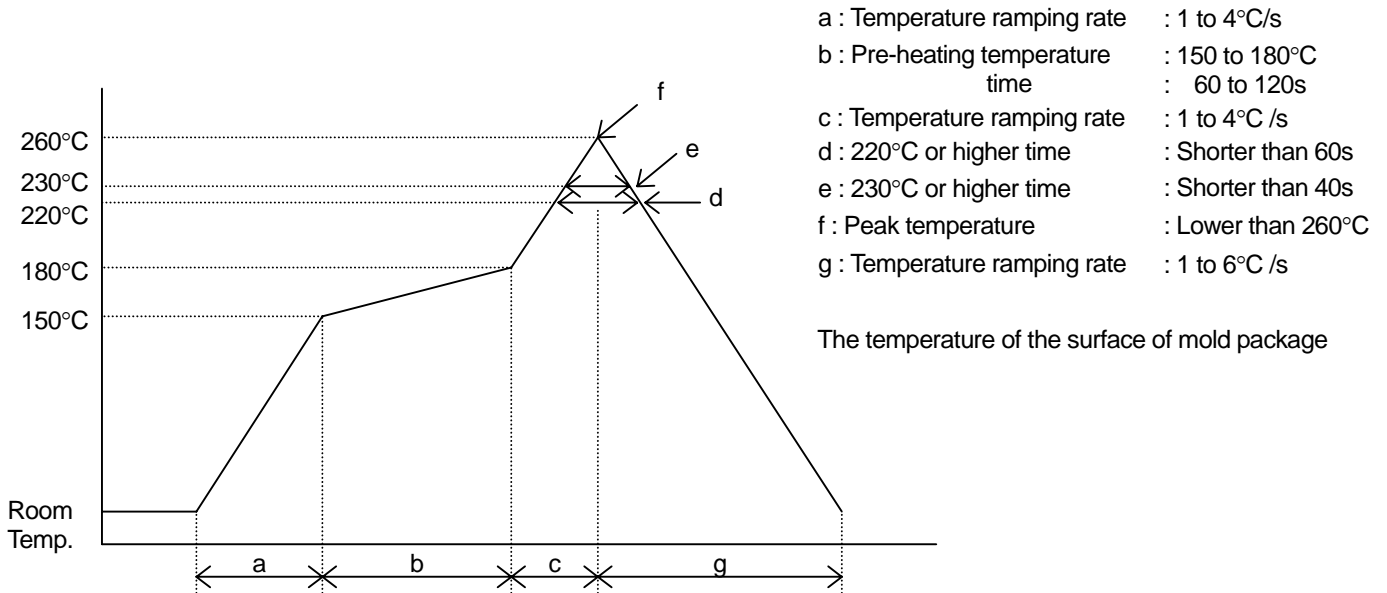
Soldering condition

The surface temperature of plastic package is lower than 260°C.

Soldering Method

1) Reflow Method

Soldering to be done within twice under the recommended condition mentioned below



2) Reflow Method (In case of infrared heating)

The temperature profile is same as the above

Avoid direct irradiation to the plastic package because it may absorb the Infrared Radiation and its surface temperature will be higher than the lead.

3) The other method

Avoid rapid heating up like dipping the devices directly into the melting solder or vapor phase method (VPS).

Solder the device in short time as soon as possible.

If the device is heated and kept in high temperature for longer time, its reliability would be affected.

2. Cleaning

Avoid washing the device after soldering by reflow method.

3. Attention in handling

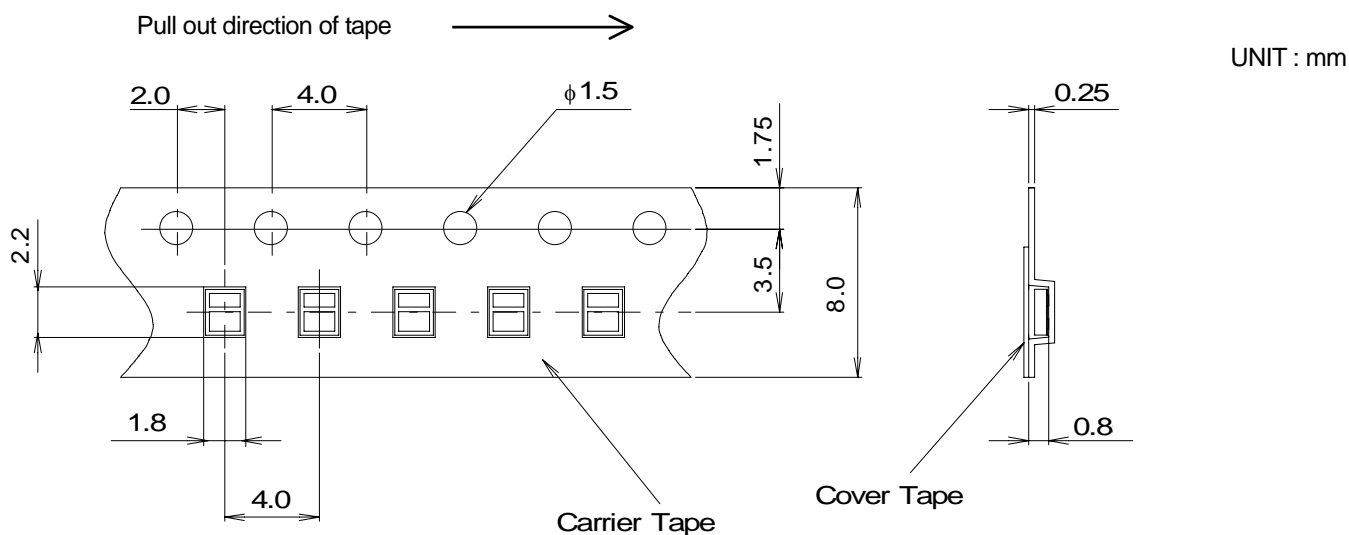
- 1) Treat not to touch the lens surface.
- 2) Avoid dust and any other foreign materials on the lens surface such as paint, bonding material, etc.
- 3) Never to apply reverse voltage (V_{EC}) of more than 6V on the photo transistor when measuring the characteristics or adjusting the system. If applied, it causes to lower the sensitivity.
- 4) When mounting, special care has to be taken on the mounting position and tilting of the device because it is very important to place the device to the optimum position to the object.

4. Storage

Mount the device as soon as possible after opening the envelope. In order to prevent from degradation by the moisture at the reflow process, the device is contained in damp proof packaging.

1. Taping Size

- 1) Carrier tape is used with Styrene type Carbonated Plastic.
- 2) Cover tape is used with electro statistically prevention treated Polyester type tape.
- 3) Product taping direction is to place the index mark against the pull out direction of the tape as in the drawing.



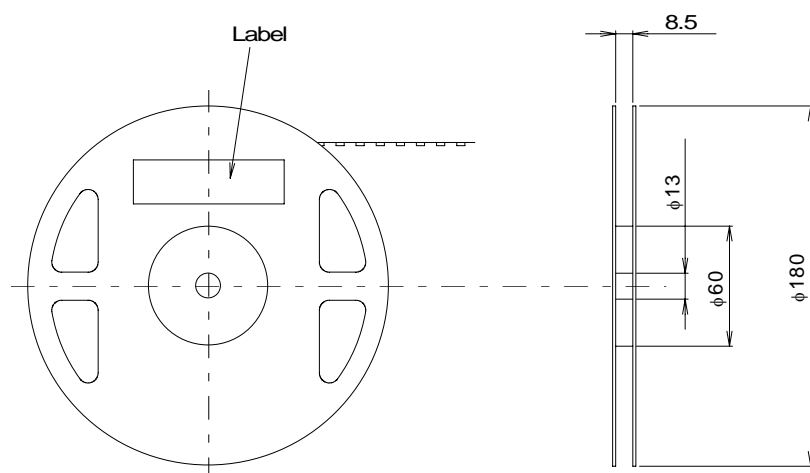
2. Taping Strength

Pull up the cover tape from the carrier tape, and when the opening angle comes around 10 to 15°, and the peeling-off strength is to be within the power of 20 to 70g.

3. Packaging

- 1) The taped products are to be rolled up on the taping reel as on the drawing.
- 2) Rolling up specification
 - 2-1) Start rolling : Carrier tape open space more than 20 Pieces.
 - 2-2) End of rolling : Carrier tape open space more than 20 Pieces, and 2 round of reel space at the cover tape only.
- 3) Taping quantity : 2,000 Pieces.
- 4) Seal off after putting each reels in a damp proof bag with silica gel.

Unit : mm



[CAUTION]
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